

TSM60N1R4

600V, 3.3A, 1.4 |
N-Channel Power MOSFET

TO-252 (DPAK)



TO-251 (IPAK)



Pin Definition:

1. Gate
2. Drain
3. Source

Key Parameter Performance

Parameter	Value	Unit
V_{DS}	600	V
$R_{DS(on)}$ (max)	1.4	
Q_g	7.7	nC

Features

- ✓ Super-Junction technology
- ✓ High performance due to small figure-of-merit
- ✓ High ruggedness performance
- ✓ High commutation performance

Application

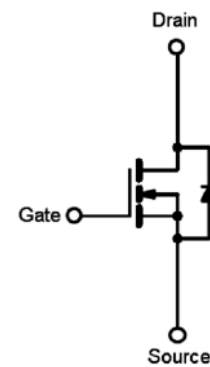
- ✓ Power Supply
- ✓ Lighting

Ordering Information

Part No.	Package	Packing
TSM60N1R4CH C5G	TO-251	75pcs / Tube
TSM60N1R4CP ROG	TO-252	2.5kpcs / 13_Reel

Note: *G_ denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	600	V
Gate-Source Voltage	V_{GS}	± 30	V
Continuous Drain Current ^(Note 1)	I_D	3.3	A
Pulsed Drain Current ^(Note 2)			
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	P_{DTOT}	38	W
Single Pulsed Avalanche Energy ^(Note 3)	E_{AS}	64	mJ
Single Pulsed Avalanche Current ^(Note 3)	I_{AS}	1.6	A
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150	$^\circ\text{C}$

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R_{\theta JC}$	3.3	$^\circ\text{C/W}$
Junction to Ambient Thermal Resistance	$R_{\theta JA}$	62	$^\circ\text{C/W}$

Electrical Specifications (T_C = 25°C unless otherwise noted)

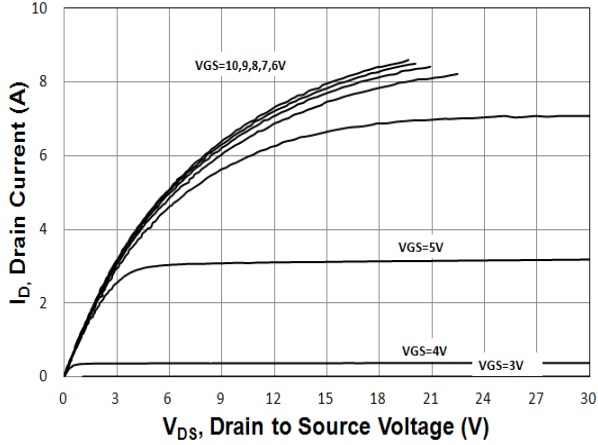
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static (Note 4)						
Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250μA	BV _{DSS}	600	--	--	V
Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	V _{GS(TH)}	2	3	4	V
Gate Body Leakage	V _{GS} = ±30V, V _{DS} = 0V	I _{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V _{DS} = 600V, V _{GS} = 0V	I _{DSS}	--	--	1	μA
Drain-Source On-State Resistance	V _{GS} = 10V, I _D = 2A	R _{DS(ON)}	--	0.88	1.4	
Dynamic (Note 5)						
Total Gate Charge	V _{DS} = 380V, I _D = 3.3A, V _{GS} = 10V	Q _g	--	7.7	--	nC
Gate-Source Charge		Q _{gs}	--	1.9	--	
Gate-Drain Charge		Q _{gd}	--	2.8	--	
Input Capacitance	V _{DS} = 100V, V _{GS} = 0V, f = 1.0MHz	C _{iss}	--	370	--	pF
Output Capacitance		C _{oss}	--	34	--	
Gate Resistance	f = 1MHz, open drain	R _g	--	3.4	--	
Switching (Note 6)						
Turn-On Delay Time	V _{DD} = 380V, R _{GEN} = 25 , I _D = 3.3A, V _{GS} = 10V,	t _{d(on)}	--	14	--	ns
Turn-On Rise Time		t _r	--	22	--	
Turn-Off Delay Time		t _{d(off)}	--	24	--	
Turn-Off Fall Time		t _f	--	20	--	
Source-Drain Diode (Note 4)						
Forward On Voltage	I _S = 3.3A, V _{GS} = 0V	V _{SD}	--	--	1.4	V
Reverse Recovery Time	V _R = 200V, I _S = 2A dI _F /dt = 100A/μs	t _{rr}	--	163	--	ns
Reverse Recovery Charge		Q _{rr}	--	1	--	nC

Notes:

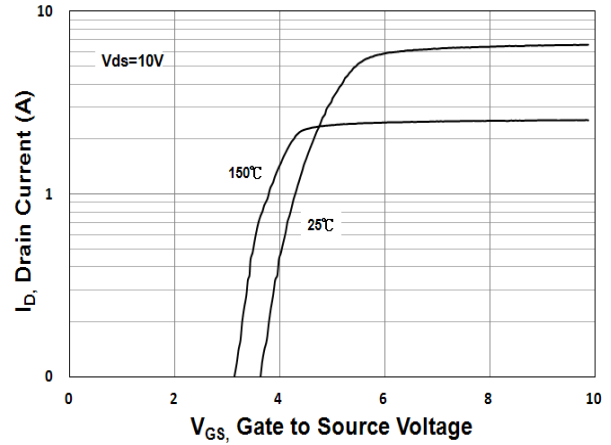
1. Current limited by package
2. Pulse width limited by the maximum junction temperature
3. L = 50mH, I_{AS} = 1.6A, V_{DD} = 50V, R_G = 25| , Starting T_J = 25°C
4. Pulse test: PW ≧300μs, duty cycle ≧2%
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

Electrical Characteristics Curves

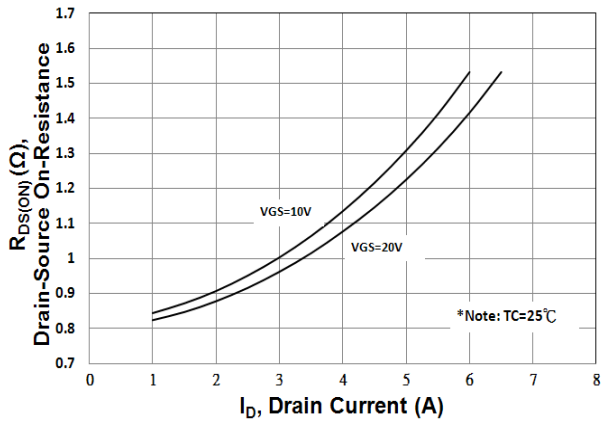
Output Characteristics



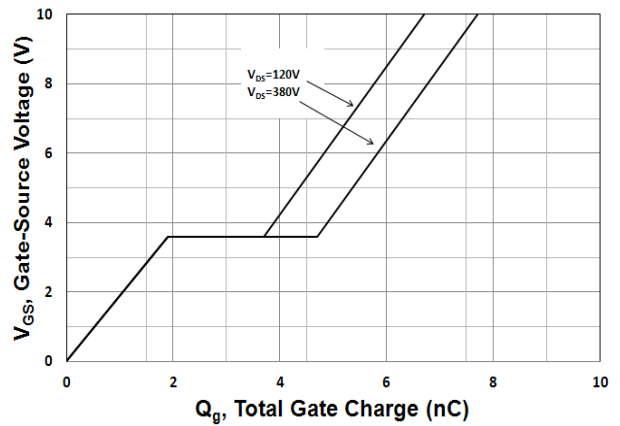
Transfer Characteristics



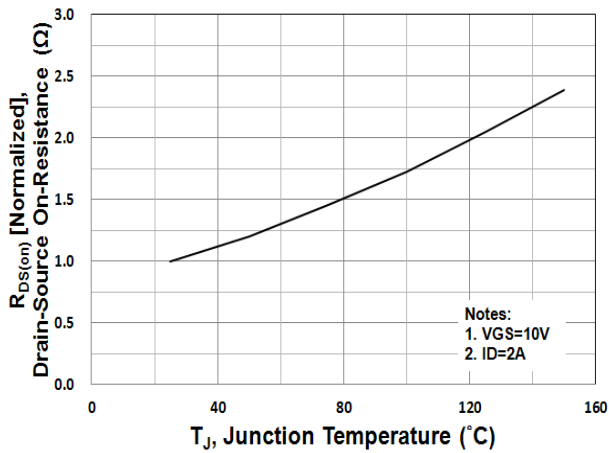
On-Resistance vs. Drain Current



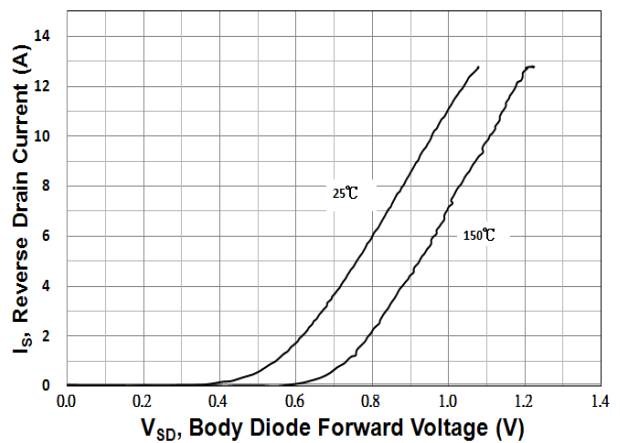
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature

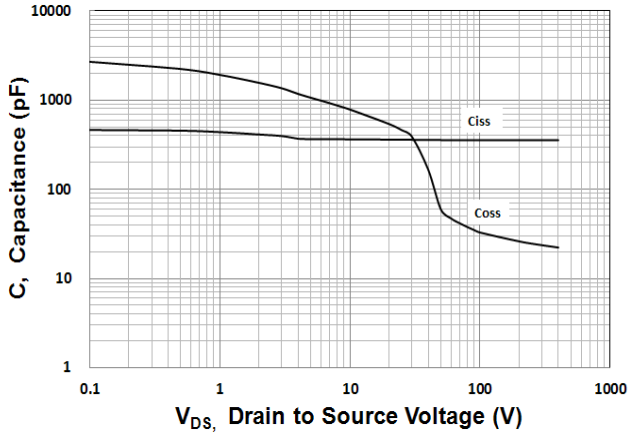


Source-Drain Diode Forward Current vs. Voltage

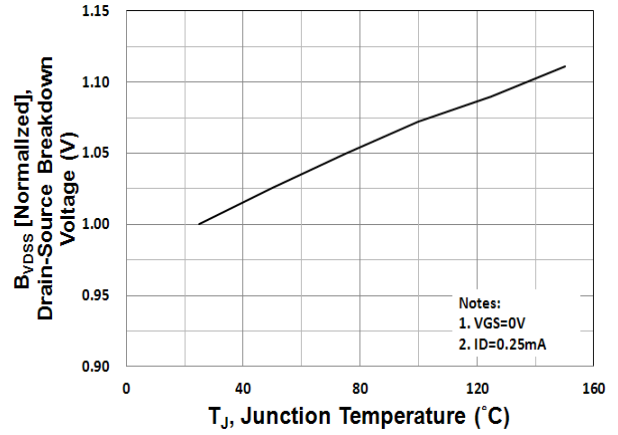


Electrical Characteristics Curves

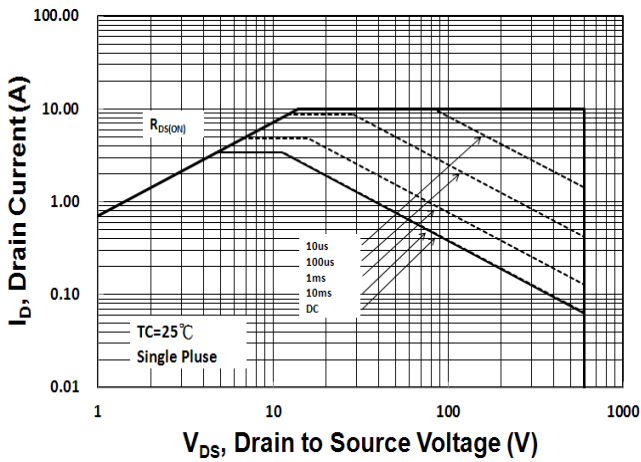
Capacitance vs. Drain-Source Voltage



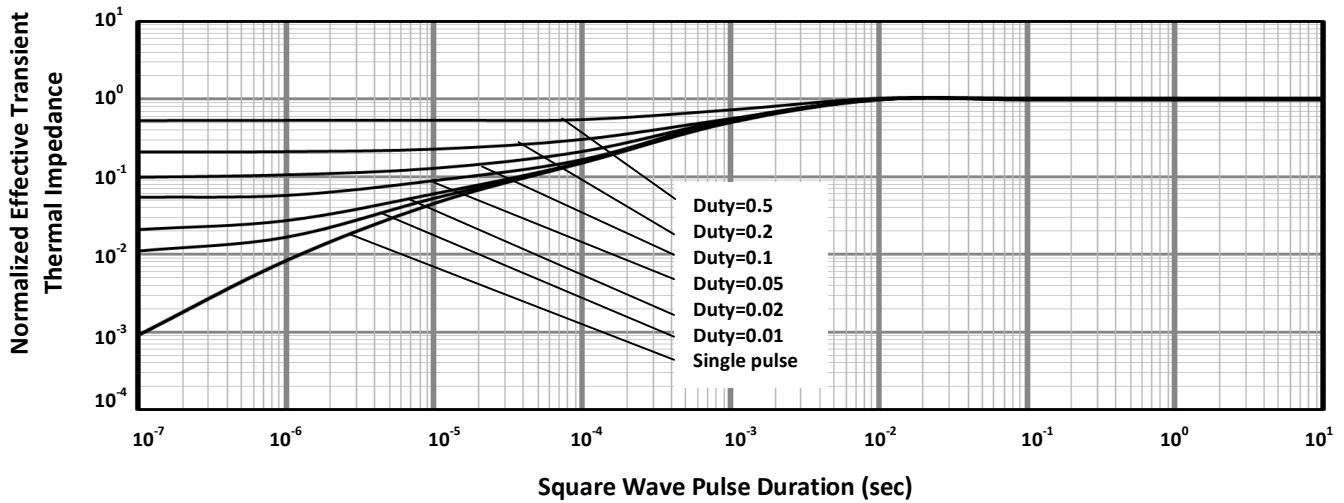
BV_{DSS} vs. Junction Temperature



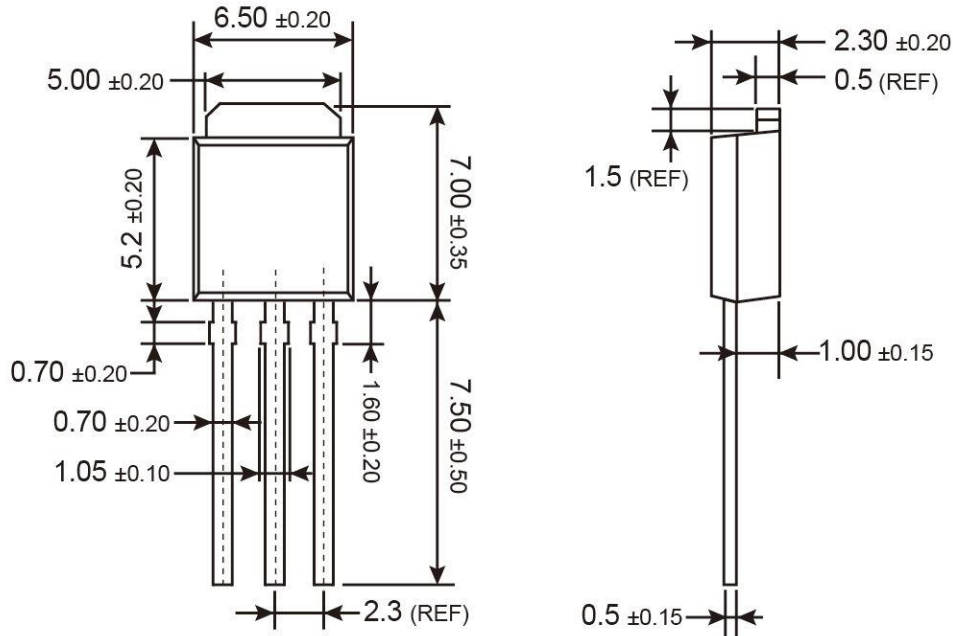
Maximum Safe Operating Area (DPAK/IPAK)



Normalized Thermal Transient Impedance, Junction-to-Case (DPAK/IPAK)

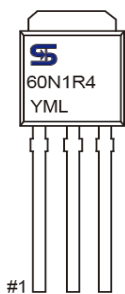


TO-251 (IPAK) Mechanical Drawing



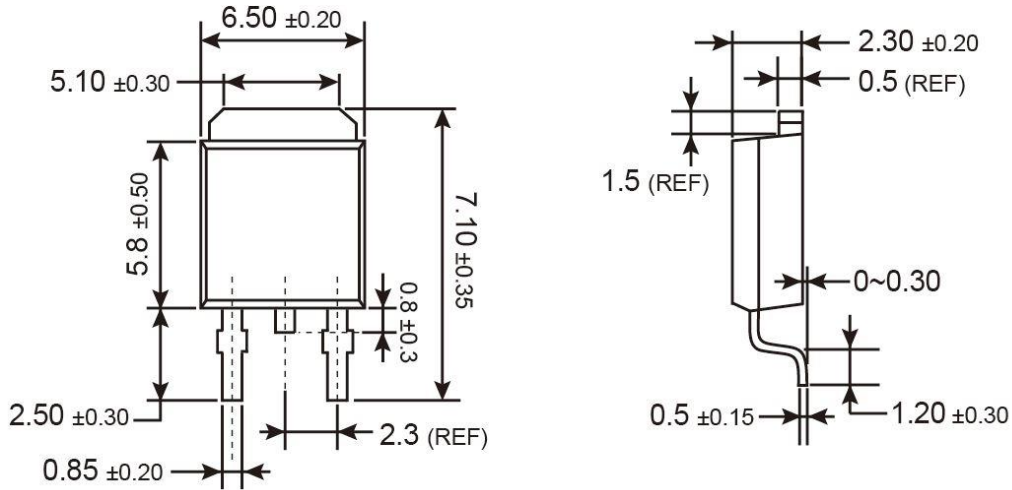
Unit: Millimeter

Marking Diagram



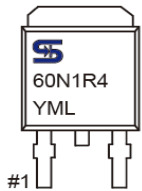
- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

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Unit: Millimeters

Marking Diagram



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